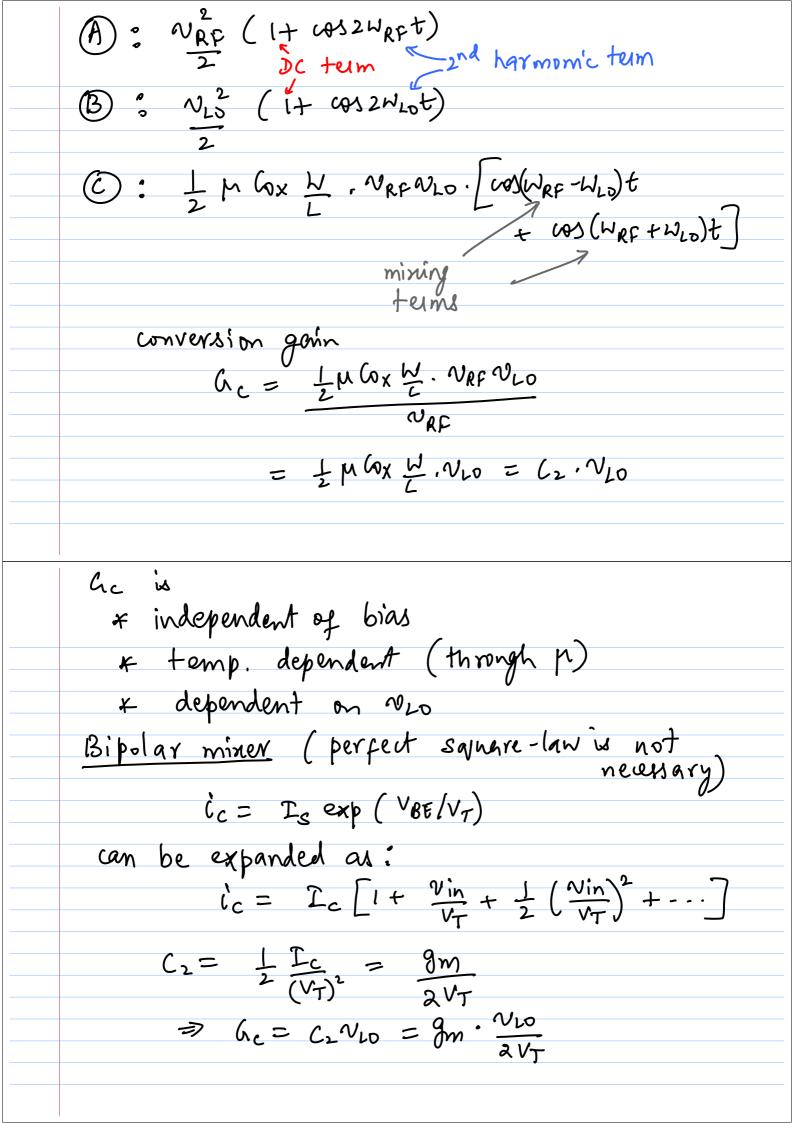


example 2 CB NEF CB NLO + vgs = VAF - VLO * RBias = large enough so that a) min. loading b) min noue & Assume VBias, I bias Vsias D Ibias & L are chosen such that ? ID = I M COX W (Vas-VT) is valid * short-channel devices are inferior VBias, Ibias chosen to avoid sub-threshold operation (exponential) ID = IM Cox W [(VBias-VT) + (NRF UDWRFT - NLO NOW LOT)] Expand into 3 terms: (i): \frac{1}{2} \mu \longred \frac{W}{L} \left[V_{\text{8ias}} - V_{\text{T}} \right]^2 \Rightarrow DC bias term (ii): Lynlox W. X (VBias-VT), (NRF MOWRFT-NLOWSWLOT) = gm (NRF USWRFT - NLO USS WLOT) > pundamental gain terms (iii): 1 M COX W [VRF LOSWRFT - NLO LOSWLOT] = I MOX W NRF WWWRFT + NO WS WLOT -2NRFNIO WSWRFT. WSWLOT



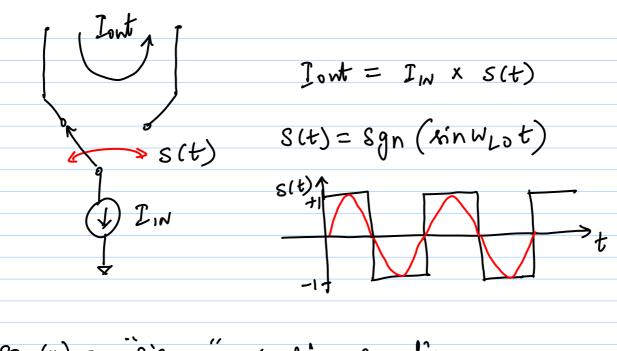
* Rewrite Gamos as: $G_{CM0}s = I_{p}G_{0} \times H_{p}(V_{814S}-V_{T}) \cdot \frac{\omega_{LO}}{(V_{814S}-V_{T})}$ $\frac{2 \text{ gm } \text{ VLO}}{2 \text{ VDSAT}} = \frac{3 \text{ m } \text{ (BJT)} \cdot \text{ VLO}}{2 \text{ VT}} \cdot \frac{2 \text{ VD.SAT}}{3 \text{ VLO}}$ $\frac{1}{2 \text{ Gc MDS}} = \frac{3 \text{ m } \text{ (BJT)} \cdot \text{ VLO}}{2 \text{ VT}} \cdot \frac{2 \text{ VD.SAT}}{3 \text{ m } \text{ (MDS)} \cdot \text{ VLO}}$ = 9m (BJT) VD.SAT > For same 9m (MOS) VT 9m, BJT has higher hc Issues with 2-port miners: -> No isolation between LOKRF (2-port). -> generation of undesired spurs (multiplication) Multiplier-based mixers * ideally generate only desired IM product

* 3-port miners => good isolation between

12F ID & TC RF, LO & IF x cmos - excellent switches Single-balanced mixer Based on "Gilbert multiplier topology enough to switch

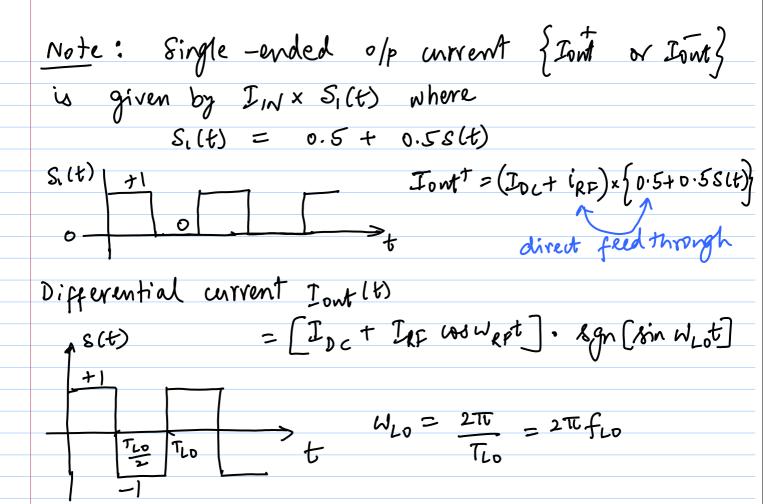
or Inc + Irr us West)

between two rides.



$$Sgn(x) = Signum'' \sim sign function$$

$$= \begin{cases} -1 & \forall x < 0 \\ 0 & x = 0 \\ +1 & \forall x > 0 \end{cases}$$



Fourier Series of
$$S(t)$$
:

$$S(t) = \frac{a_0}{2} + \sum_{n=1}^{\infty} \left[a_n \cos(n\omega_{Lo}t) + b_n \sin(n\omega_{Lo}t) \right]$$

$$\frac{a_0}{2} = 0 \quad \left(DC \text{ average} \right)$$

$$a_n = \frac{2}{T_{Lo}} \int_{0}^{T_{Lo}} sgn(t) \cos(n\omega_{Lo}t) dt = 0 \quad \forall n \left\{ sgn(t) \right\}$$

$$b_n = \frac{2}{T_{Lo}} \int_{0}^{T_{Lo}} sgn(t) \cdot \sin(n\omega_{Lo}t) dt$$

$$= 2 \cdot \frac{2}{T_{Lo}} \int_{0}^{T_{Lo}/L} sin(n\omega_{Lo}t) dt$$

$$= \frac{2}{T_{Lo}} \left[1 - cosn(t) \right]_{0}^{T_{Lo}/L}$$

$$\therefore b_n = \left\{ \begin{array}{c} 0 \quad \forall \quad even \quad n \\ \frac{4}{n\pi} \quad fr \quad odd \quad n \end{array} \right.$$

$$\therefore S(t) = \frac{4}{T_{Lo}} \left[sin\omega_{Lo}t + \frac{1}{3} sin s\omega_{Lo}t + \frac{1}{3} sin s\omega$$

4 Doc Sin West + I sin 3 Whot + ... "Lo feed through" feed through of) => 4 IRF. [WSHRFT SinWLot + 1 WSWRFTSM 3WLot +... = 4 IRF. 1 Sin (WLO-WRF)t + Sin (WLO+WRF)t + 1 Sin (3 WLO-WRF)t + 1 Sin (3WLO +4RF)t + - - -] = 2 FRF (sin (WLO-WRF)t + sin (WLO+WRF)t To lower sideband upper sideband + higher order terms?

int (t) = 2 frs [sin (WLO-WRF)t + rin (WLO+WRF)t]

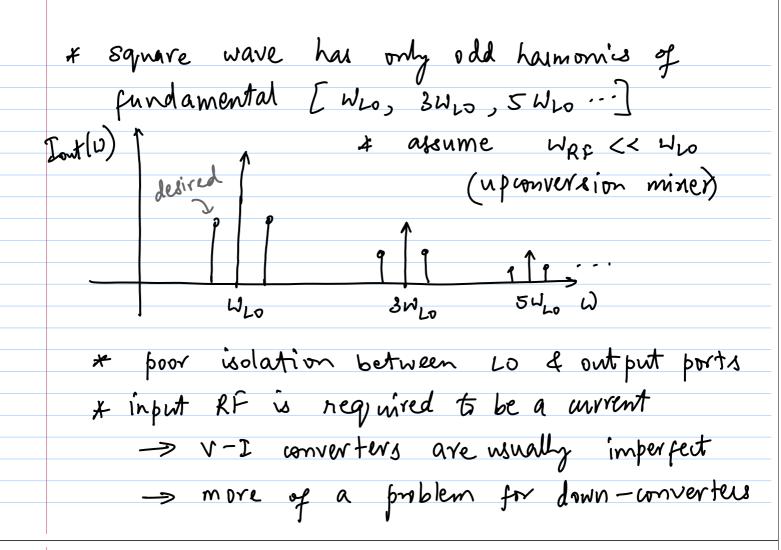
+ [higher order mining terms]

+ [LOGLO harmonic feed through terms]

close to desired

term in case of Tx

- cannot be filtered out



* no RF feed through assumes perfect M,-M3 most dring

* Immediate switching requires vo wave form

zero crossings to win vide, otherwise

-> LO diff. pair simultaneously on

-> RF current is "wasted" as common-mode

signal (a, I, NF1)